

# NX8349TS

LASER DIODE

1 310 nm AlGaInAs MQW-DFB LASER DIODE FOR 10 Gb/s APPLICATION

## DESCRIPTION

<R> The NX8349TS is 1 310 nm Multiple Quantum Wells (MQW) structured Distributed Feed-Back (DFB) laser diode TOSA (transmitter optical subassembly) with InGaAs monitor PIN-PD in a receptacle type package designed for SFP+/XFP transceiver.

### **FEATURES**

- Internal optical isolator
- Optical output power
- Low threshold current
- Wide operating temperature range
- InGaAs monitor PIN-PD

### **APPLICATIONS**

- 10 G BASE-LW/LR
- 10 G Fibre Channel

- $P_{\rm f} = -3 \, \rm dBm$
- $I_{th} = 8 \text{ mA TYP.}$  (a)  $T_C = 25^{\circ}C$
- $T_{\rm C} = -5 \text{ to } +95^{\circ}{\rm C}$

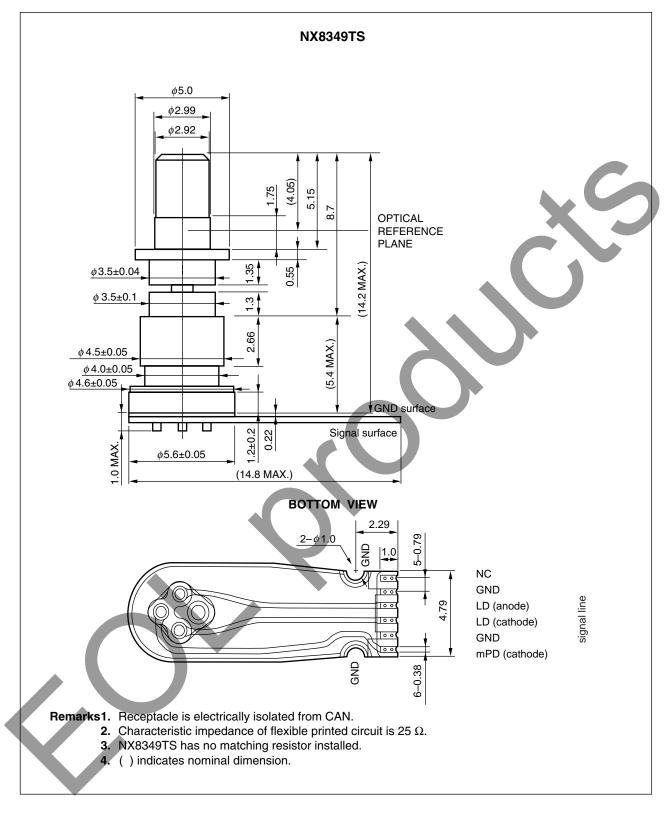
The mark <R> shows major revised points.

The revised points can be easily searched by copying an "<R>" in the PDF file and specifying it in the "Find what:" field.



R08DS0002EJ0200 Rev.2.00 Dec 13, 2013

## PACKAGE DIMENSIONS (UNIT: mm)





# ORDERING INFORMATION

Part Number	Receptacle Type	Note
NX8349TS	LC, Electrically isolated, type 1	Differential input with short length flexible PCB,
		without matching resistor



# ABSOLUTE MAXIMUM RATINGS

Parameter	Symbol	Ratings	Unit
Storage Temperature	T <sub>stg</sub>	-40 to +95	°C
Operating Case Temperature	T <sub>C</sub>	–5 to +95	°C
Forward Current of LD	I <sub>FLD</sub>	120	mA
Reverse Voltage of LD	V <sub>RLD</sub>	2	V
Forward Current of PD	I <sub>FPD</sub>	10	mA
Reverse Voltage of PD	V <sub>RPD</sub>	15	V
Soldering Temperature	T <sub>sld</sub>	350 (10 sec.)	°C
(Flexible Printed Circuit)			
Optical Output Power	P <sub>f</sub>	5	mW



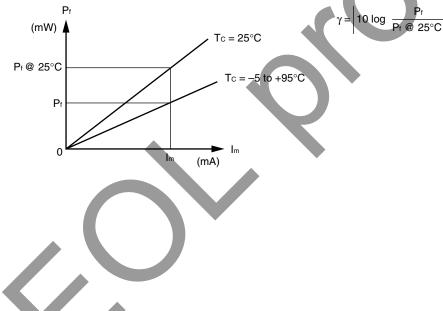
# ELECTRO-OPTICAL CHARACTERISTICS (Tc = -5 to +95°C, BOL, unless otherwise specified)

Parameter	Symbol	Conditions	MIN.	TYP	MAX.	Unit
Mean Optical Output Power	Pf			-3		dBm
Peak Emission Wavelength	λρ	CW, P <sub>f</sub> = -3 dBm	1 290		1 330	nm
Spectral Width	Δλ	CW, $P_f = -3 \text{ dBm}$ , 20 dB down			1	nm
Side Mode Suppression Ratio	SMSR	CW, P <sub>f</sub> = -3 dBm	35			dB
Threshold Current	I <sub>th</sub>	CW, T <sub>C</sub> = 25°C		8	15	mA
		CW	2		30	
Differential Efficiency	$\eta_{d}$	CW, $P_f = -3 \text{ dBm}$ , $T_C = 25^{\circ}\text{C}$	0.020	0.033	0.040	W/A
		CW, $P_f = -3 \text{ dBm}$	0.012		0.060	
Temperature Dependence of Differential Efficiency	$arDelta\eta_{d}$	$\Delta \eta_{\rm d} = 10 \log \frac{\eta_{\rm d}}{\eta_{\rm d} (@25^{\circ}{\rm C})}$	-3.5		1.5	dB
Operation Voltage	V <sub>op</sub>	CW, $P_f = -3 \text{ dBm}$	0.5		2.2	V
Monitor Current	l <sub>m</sub>	CW, P <sub>f</sub> = -3 dBm	70		700	μA
Monitor Dark Current	I <sub>D</sub>	$V_R$ = 3.3 V, $T_C$ = 25°C			10	nA
		V <sub>R</sub> = 3.3 V			500	
Rise Time	tr	20-80% * <b>1</b>			50	ps
Fall Time	t <sub>f</sub>	20-80% *1			50	ps
Monitor PD Terminal	Ct	V <sub>R</sub> = 3.3 V, f = 1 MHz		6	20	pF
Capacitance						
Relative Intensity Noise	RIN	*1			-128	dB/Hz
Tracking Error*2	γ		-1.0		1.0	dB

[dB]

Notes: \*1. 9.95/10.3/10.5 Gb/s, PRBS 2<sup>31</sup>-1, NRZ, Duty Cycle = 50%

\*2. Tracking Error:  $\boldsymbol{\gamma}$ 





#### REFERENCE

Document Name	Document No.	
Opto-Electronics Devices Pamphlet <sup>*1</sup>	PX10160E	

Notes: \*1. Published by the former NEC Electronics Corporation.

#### SAFETY INFORMATION ON THIS PRODUCT





AVOID EXPOSURE-Invisible Laser Radiation is emitted from this aperture

Warning Laser Beam	A laser beam is emitted from this diode during operation. The laser beam, visible or invisible, directly or indirectly, may cause injury to the eye or loss of
	eyesight.
	Do not look directly into the laser beam.
	Avoid exposure to the laser beam, any reflected or collimated beam.
Caution GaAs Products	This product uses gallium arsenide (GaAs). GaAs vapor and powder are hazardous to human health if inhaled or ingested, so please observe the following points.
	• Follow related laws and ordinances when disposing of the product. If there are no applicable laws and/or ordinances, dispose of the product as recommended below.
	<ol> <li>Commission a disposal company able to (with a license to) collect, transport and dispose of materials that contain arsenic and other such industrial waste materials.</li> </ol>
	<ol><li>Exclude the product from general industrial waste and household garbage, and ensure that the product is controlled (as industrial waste subject to special control) up until final disposal.</li></ol>
	• Do not burn, destroy, cut, crush, or chemically dissolve the product.
	• Do not lick the product or in any way allow it to enter the mouth.
Caution Optical Fiber	A glass-fiber is attached on the product. Handle with care.
	<ul> <li>When the fiber is broken or damaged, handle carefully to avoid injury from the damaged part or fragments.</li> </ul>

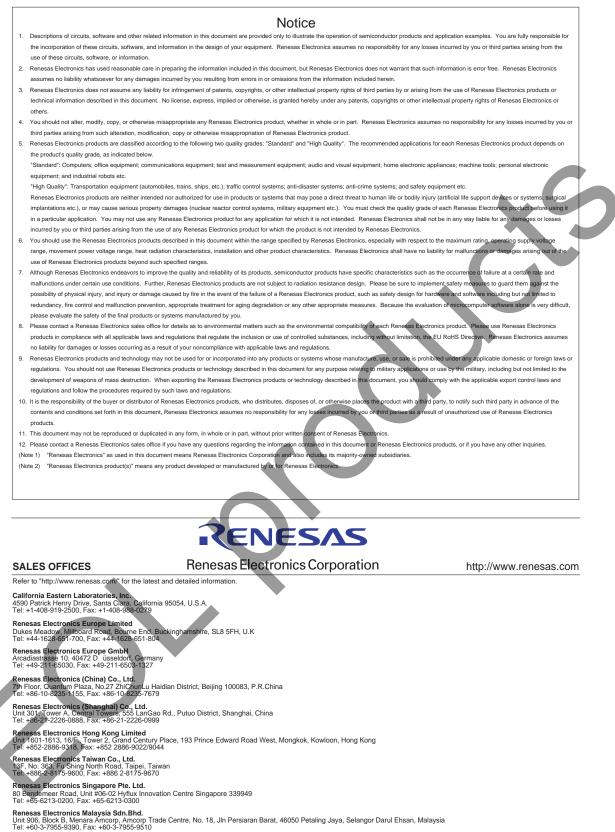




Revision	History
110101011	I HOLOI Y

## NX8349TS Data Sheet

		Description		
Rev.	Date	Page Summary		
1.00	Jul 26, 2010	-	First edition issued	
2.00	Dec 13, 2013	Throughout	Deletion of NX8349YK and NX8349XK	



Renesas Electronics Korea Co., Ltd. 12F., 234 Teheran-ro, Gangnam-Gu, Seoul, 135-080, Korea Tel: +82-2-558-3737, Fax: +82-2-558-5141